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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/696,619	10/25/2000	Tetsuo Tsutsui	SEL 220	3946

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[REDACTED] EXAMINER

COLON, GERMAN

[REDACTED] ART UNIT [REDACTED] PAPER NUMBER

2879

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Please find below and/or attached an Office communication concerning this application or proceeding.

## Office Action Summary

	Application No.	Applicant(s)
	09/696,619	TSUTSUI ET AL.
	Examiner German Colón	Art Unit 2879

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

### Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).
- Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

### Status

- 1) Responsive to communication(s) filed on 02 December 2002.
- 2a) This action is **FINAL**.                  2b) This action is non-final.
- 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

### Disposition of Claims

- 4) Claim(s) 1-12 is/are pending in the application.
- 4a) Of the above claim(s) \_\_\_\_\_ is/are withdrawn from consideration.
- 5) Claim(s) \_\_\_\_\_ is/are allowed.
- 6) Claim(s) 1-12 is/are rejected.
- 7) Claim(s) \_\_\_\_\_ is/are objected to.
- 8) Claim(s) \_\_\_\_\_ are subject to restriction and/or election requirement.

### Application Papers

- 9) The specification is objected to by the Examiner.
- 10) The drawing(s) filed on 02 December 2002 is/are: a) accepted or b) objected to by the Examiner.  
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
- 11) The proposed drawing correction filed on \_\_\_\_\_ is: a) approved b) disapproved by the Examiner.  
If approved, corrected drawings are required in reply to this Office action.
- 12) The oath or declaration is objected to by the Examiner.

### Priority under 35 U.S.C. §§ 119 and 120

- 13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) All b) Some \* c) None of:
1. Certified copies of the priority documents have been received.
  2. Certified copies of the priority documents have been received in Application No. \_\_\_\_\_.
  3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
- \* See the attached detailed Office action for a list of the certified copies not received.
- 14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).  
a) The translation of the foreign language provisional application has been received.
- 15) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.

### Attachment(s)

- |  |   |
|--|---|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892)                  | 4) <input type="checkbox"/> Interview Summary (PTO-413) Paper No(s). _____  |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948)         | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152) |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449) Paper No(s) _____ | 6) <input type="checkbox"/> Other: _____                                    |

## DETAILED ACTION

### *Response to Amendment*

1. The Amendment, filed on December 02, 20002, has been entered and acknowledged by the Examiner.

### *Claim Rejections - 35 USC § 103*

2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

3. Claims 1-4 are rejected under 35 U.S.C. 103(a) as being unpatentable over Antoniadis et al. (US 6,366,017) in view of Onitsuka et al. (US 6,049,167).

Regarding claim 1, Antoniadis discloses a light-emitting device comprising: an opaque electrode **12** over a substrate **10**; an EL layer **16** over the opaque electrode; and a transparent electrode **20** over the EL layer; wherein each of said EL layer **16** and said transparent electrode **20** has a film thickness in which there is no occurrence of a guided light. Antoniadis fails to disclose "an inert gas filled in a space between the transparent electrode and a cover material".

However, in the same field of endeavor, Onitsuka discloses an EL device comprising an EL layer being sandwiched between a transparent electrode and an opaque electrode, where an inert gas fills a space between the transparent electrode and a cover material, with the purpose of avoiding the presence of moisture that can cause separation between the EL layer and the electrode layers or degradation of the constituent materials, generating dark spots or failing to

Art Unit: 2879

maintain light emission (see Col. 1, lines 27-32). Therefore, it would have been obvious to anyone of ordinary skill in the art at the time the invention was made to use Onitsuka's teachings to improve the EL device of Antoniadis, in order to avoid moisture that can cause separation of the EL and electrodes layers or degradation of the constituent materials, generating dark spots or failing to maintain light emission.

Regarding claim 2, Antoniadis-Onitsuka discloses an EL device wherein the thickness (d) of the EL layer and transparent electrode satisfies a formula  $d \leq \lambda/(4n)$  when a light with a wavelength “ $\lambda$ ” generated by the EL layer passes through a medium with a refractive index “ $n$ ”. The Examiner notes that the claim does not make reference to a particular wavelength; accordingly, any wavelength can exemplify the claimed wavelength. Antoniadis-Onitsuka teaches the EL layer made of either Alq3 [ $n=1.7$ ] (see '017, Col. 3, lines 21-24) and the transparent electrode made of ITO [ $n=1.95$ ] (see '017, Col. 3, line 55 and Col. 4, line 12). The preferred thickness of the EL layer is 100 nm (see '017, Col. 5, line 55) and that of the transparent electrode ranges from 1-50 nm (see '017, Col. 3, lines 55-57). The disclosed thickness values satisfy the claimed thickness equation (where  $d \leq 103$  nm for Alq3 and  $d \leq 90$  nm for ITO, for a wavelength in the red spectrum of 700 nm).

Referring to claim 3, Antoniadis discloses a light-emitting device comprising: an opaque electrode **12** over a substrate **10**; an EL layer **16** over the opaque electrode, said EL layer having a light-emitting material; a transparent electrode **20** over the EL layer; and a buffer layer **18** (or **14**) provided between said light-emitting layer and said transparent electrode or between said light-emitting layer and said opaque electrode; wherein each of said EL layer **16** and said transparent electrode **20** has a film thickness in which there is no occurrence of a guided light.

Art Unit: 2879

Antoniadis fails to disclose “an inert gas filled in a space between the transparent electrode and a cover material”.

However, in the same field of endeavor, Onitsuka discloses an EL device comprising an EL layer being sandwiched between a transparent electrode and an opaque electrode, where an inert gas fills a space between the transparent electrode and a cover material, with the purpose of avoiding the presence of moisture that can cause separation between the EL layer and the electrode layers or degradation of the constituent materials, generating dark spots or failing to maintain light emission (see Col. 1, lines 27-32). Therefore, it would have been obvious to anyone of ordinary skill in the art at the time the invention was made to use Onitsuka’s teachings to improve the EL device of Antoniadis, in order to avoid moisture that can cause separation of the EL and electrodes layers or degradation of the constituent materials, generating dark spots or failing to maintain light emission.

Referring to claim 4, claim 4 is rejected over the reasons stated in the rejection of claim 2 above.

5. Claims 5-12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Shibata et al. (US 6,147,451) in view of Onitsuka et al. (US 6,049,167), further in view of Codama (US 6,091,078) and Arai (US 6,163,110).

Regarding claim 5, Shibata discloses a light-emitting device having a pixel portion comprising a semiconductor device and an EL element electrically connected to the semiconductor device formed on a substrate (see Fig. 5 and Col. 3, lines 33-38), said EL element comprising:

an opaque electrode 22; an EL layer 23 over the opaque electrode; and a transparent electrode 24 over the EL layer. Shibata fails to disclose "an inert gas filled in a space between the transparent electrode and a cover material".

However, in the same field of endeavor, Onitsuka discloses an EL device comprising an EL layer being sandwiched between a transparent electrode and an opaque electrode, where an inert gas fills a space between the transparent electrode and a cover material, with the purpose of avoiding the presence of moisture that can cause separation between the EL layer and the electrode layers or degradation of the constituent materials, generating dark spots or failing to maintain light emission (see Col. 1, lines 27-32). Therefore, it would have been obvious to anyone of ordinary skill in the art at the time the invention was made to use Onitsuka's teachings to improve the EL device of Shibata, in order to avoid moisture that can cause separation of the EL and electrodes layers or degradation of the constituent materials, generating dark spots or failing to maintain light emission.

Shibata-Onitsuka discloses an EL layer made of N,N'-Diphenyl-N,N'-di( $\alpha$ -naphthyl)benzidine (see '451, Col. 5, lines 21-22) with a thickness of 20 nm (see '451, Col. 4, line 60) and a transparent electrode made of ITO (see '451, Col. 4, lines 62-63). Shibata-Onitsuka is silent regarding the index of refraction of the EL layer and the thickness of the transparent electrode.

However, Codama discloses an EL device with a transparent electrode made of ITO with a thickness of 10-500 nm, and especially about 30-300 nm, and teaches that too thick electrodes can give rise to problems including peeling, poor workability, stress failure, low light transmittance and leakage due to surface roughness. Further, Codama teaches that too thin

electrode is undesirable in film strength during manufacture, hole transporting capabilities and electric resistance (see '078, Col. 12, lines 25-34). In the same field of endeavor, Arai discloses an EL device with an organic light-emitting layer and teaches that organic EL layers usually have a refractive index of about 1.6-1.8, with an average of 1.7 (see '110, Col. 2, lines 40-42) and further teaches that with such an index of refraction, mass production of EL devices with fluctuations in light emission luminance from device to device is reduced, avoiding use of additional equipment for luminance control which provides a decrease in cost of the product and an increase in production efficiency (see '110, Col. 1, lines 30-42, 55-56, 62-67; and Col. 2, lines 1-16). Thus, it would have been obvious to one of ordinary skill in the art at the time the invention was made to use Codama's teachings of providing a transparent electrode made of ITO with a thickness of 10-500 nm (30-300 nm); and Arai's teachings of an organic EL layer with an index of refraction of 1.6-1.8 (1.7), with the purpose of (1)avoiding problems including peeling, poor workability, stress failure, low light transmittance and leakage due to surface roughness, undesirable film strength during manufacture, hole transporting capabilities and electric resistance of the transparent electrode; and (2)reducing fluctuations in light emission luminance from device to device in mass production, avoiding use of additional equipment for luminance control which provides a decrease in cost of the product and an increase in production efficiency.

Shibata-Onitsuka in view of Codama-Arai discloses an EL layer and a transparent electrode having a film thickness in which there is no occurrence of guided light.

Regarding claim 6, Shibata-Onitsuka-Codama-Arai discloses an EL device wherein the thickness (d) of the EL layer and transparent electrode satisfies a formula  $d \leq \lambda/(4n)$  when a light with a wavelength " $\lambda$ " generated by the EL layer passes through a medium with a refractive

index "n". The Examiner notes that the claim does not make reference to a particular wavelength; accordingly, any wavelength can exemplify the claimed wavelength. Shibata-Onitsuka-Codama-Arai teaches the EL layer with [n=1.7] (see '110, Col. 2, lines 40-42) and the transparent electrode made of ITO [n=1.95] (see '451, Col. 4, lines 62-63). The preferred thickness of the EL layer is 20 nm (see '451, Col. 4, line 60) and that of the transparent electrode ranges from 30-300 nm (see '078 Col. 12, line 27). The disclosed thickness values satisfy the claimed thickness equation (where  $d \leq 103$  nm for n=1.7 and  $d \leq 90$  nm for ITO, for a wavelength in the red spectrum of 700 nm).

Referring to claim 7, Shibata-Onitsuka-Codama-Arai discloses a light-emitting device having a pixel portion comprising a semiconductor device and an EL element electrically connected to the semiconductor device formed on a substrate (see '451, Fig. 5 and Col. 3, lines 33-38), said EL element comprising:

an opaque electrode 22; an EL layer 23 over the opaque electrode; and a transparent electrode 24 over the EL layer; an inert gas fills a space between the transparent electrode and a cover material (see '167, Fig. 1); a buffer layer provided between said light-emitting layer and said transparent electrode or between said light-emitting layer and said opaque electrode (see '451 Fig. 5 in view of Fig. 6), wherein each of said EL layer 23 and said transparent electrode 24 has a film thickness in which there is no occurrence of a guided light. Same reason for combining stated in claim 5 applies.

Referring to claim 9, Shibata-Onitsuka-Codama-Arai discloses a light-emitting device having a pixel portion comprising:

a plurality of opaque electrodes **22** arranged in stripe shapes over a substrate (see '451, Fig. 9); an EL layer **23** over the plurality of opaque electrodes; a plurality of transparent electrodes **24** (see '451, Fig. 9 in view of Fig. 8) over the EL layer, the plurality of transparent electrodes provided in stripe shapes so as to be orthogonal to the plurality of opaque electrodes; and an inert gas fills a space between the transparent electrode and a cover material (see '167, Fig. 1), wherein each of said EL layer **23** and said transparent electrode **24** has a film thickness in which there is no occurrence of a guided light. Same reason for combining stated in claim 5 applies.

Regarding claim 11, Shibata-Onitsuka-Codama-Arai discloses a light-emitting device having a pixel portion comprising:

a plurality of opaque electrodes **22** arranged in stripe shapes over a substrate (see '451, Fig. 9); an EL layer **23** over the plurality of opaque electrodes; a plurality of transparent electrodes **24** (see '451, Fig. 9 in view of Fig. 8) over the EL layer, the plurality of transparent electrodes provided in stripe shapes so as to be orthogonal to the plurality of opaque electrodes; and an inert gas fills a space between the transparent electrode and a cover material (see '167, Fig. 1), a buffer layer provided between said light-emitting layer and said transparent electrode or between said light-emitting layer and said opaque electrode (see '451 Fig. 5 in view of Fig. 6), wherein each of said EL layer **23** and said transparent electrode **24** has a film thickness in which there is no occurrence of a guided light. Same reason for combining stated in claim 5 applies.

Regarding claims 8, 10 and 12, claims 8, 10 and 12 are rejected over the reasons stated in the rejection of claim 6.

Art Unit: 2879

***Response to Arguments***

6. Applicant's arguments with respect to claims 1-12 have been considered but are moot in view of the new ground(s) of rejection.

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

***Prior Art of Record***

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure:

Hosokawa et al., in U.S. Patent No. 5,891,554, discloses an organic EL device with an organic light-emitting layer having an index of refraction of 1.6-1.8.

***Contact Information***

Any inquiry concerning this communication or earlier communications from the examiner should be directed to German Colón whose telephone number is 703-305-5987. The examiner can normally be reached on Monday thru Friday, from 8:30 to 5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nimesh Patel can be reached on 703-305-4794. The fax phone numbers for the organization where this application or proceeding is assigned are 703-308-7382 for regular communications and 703-308-7382 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

fc  
gc  
March 8, 2003

  
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